

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LB1938T — 1ch, Low-saturation Forward/Reverse Motor Driver

Overview

The LB1938T is an H-bridge motor driver that supports low-voltage drive and features low-saturation outputs in an ultraminiature slim package. The LB1938T provides forward, reverse, brake, and standby modes controlled by two input signals, and is an optimal DC motor driver for notebook personal computers, digital cameras, cell phones, and other portable equipment.

Features

- Ultraminiature MSOP8 package (3.0mm×4.9mm×0.93mm)
- The low saturation voltage means that the voltage applied to the motor is higher and IC heat generation is reduced. This allows this IC to be used in environments with higher ambient operating temperatures.
 - Output saturation voltage (high side + low side): $V_{Osat} = 0.15V$ typical (I_O = 100mA)
- The wide usable voltage range and the low standby mode current drain of 0.1 µA make this IC optimal for battery operated equipment.
- There are no constraints on the relationship between the input signal voltage and the supply voltage. For example, this IC can be use at $V_{CC} = 3V$ and $V_{IN} = 5V$.
- Thermal protection circuit limits the drive current and prevents the IC from causing a fire or being destroyed if the IC chip temperature reaches or exceeds 180°C due to large currents flowing when the outputs are shorted due to, for example, motor layer shorting or other phenomena.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} max		10.5	V
Output current	IOUT max		800	mA
Output voltage	V _{OUT} max		V _{CC+VSF}	V
Input applied voltage	V _I H max		10	V

Continued on next page.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

LB1938T

Parameter	Symbol	Conditions	Ratings	Unit
Allowable power dissipation	Pd max	Mounted on a specified board *	400	mW
Operating temperature range	Topr		-30 to +85	°C
Storage temperature range	Tstg		-55 to +150	°C

Note *: Mounted on a specified board: 114.3mm×76.1mm×1.5mm, glass epoxy resin, wiring density 20%

Allowable Operating Range at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		2.2 to 10	V
Input high-level voltage	VIН		2.0 to 9.5	V
Input low-level voltage	VIL		-0.3 to +0.3	V

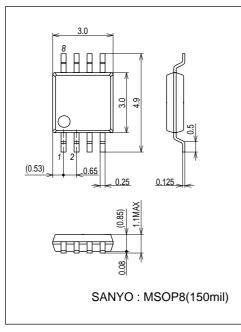
Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{CC} = 3V$

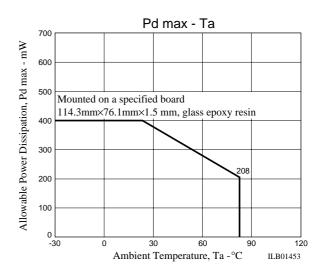
Parameter	Symbol			Ratings		
		Conditions	min	typ	max	Unit
Circuit current	ICC1	Standby		0.1	5	μA
	ICC2	Forward/reverse drive		14	19	mA
	ICC3	Brake		20	29	mA
Output saturation voltage	V _O sat1	Upper+lower I _O = 100mA for forward/reverse rotation		0.15	0.2	V
	V _O sat2	Upper+lower I _O = 300mA for forward/reverse rotation		0.35	0.5	V
	V _O sat3	Upper I _O = 100mA for braking		0.1	0.15	V
Spark killer diode forward voltage	VSF	I _O = 300mA		0.9	1.7	V
Spark killer diode inverse current	IRS	V _{OUT} = 10V		0.1	5	μA
Input current	IIN	V _{IN} = 5V		75	98	μA
Thermal protection operating temperature	TSD	Design target value *		180		°C

Note *: Design target value: Measurement with a single unit not made.

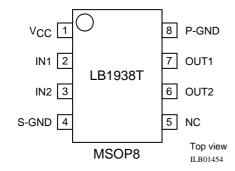
Package Dimensions

unit : mm (typ) 3245B





Pin Assignment

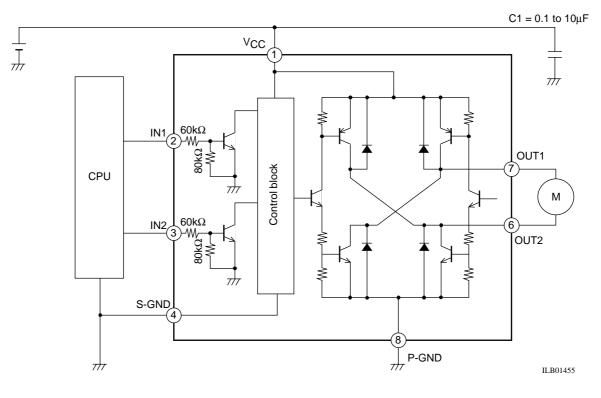


S-GND: GND for the control system P-GND: GND for the power system

Truth Table

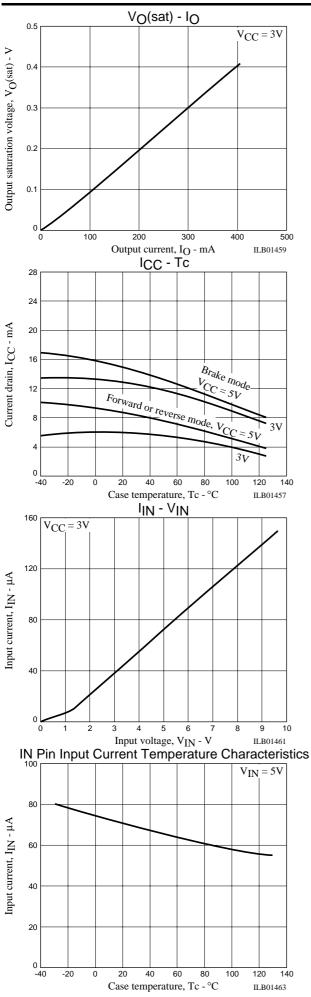
IN1	IN2	OUT1	OUT2	Mode
L	L	OFF	OFF	Standby
н	L	Н	L	Forward rotation
L	Н	L	Н	Reverse rotation
н	Н	Н	Н	Brake

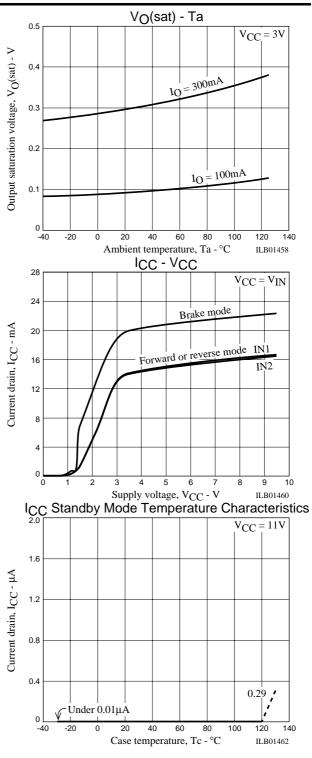
Sample Application Circuit



Cautions:

- V_{CC} and GND lines suffer substantial fluctuation in the current quantity, causing a problem of line oscillation in certain cases. In this case, take following points into account:
 - (1) Use a thick and short wiring to reduce the wiring inductance.
 - (2) Insert a capacitor with satisfactory frequency characteristics near IC.
 - (3) Connect S-GND to the control system GND on the CPU side and P-GND to the power system GND.





- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of June, 2007. Specifications and information herein are subject to change without notice.